Amendment dated August 29, 2008

Reply to Office Action of April 29, 2008

AMENDMENTS TO THE CLAIMS

1. (Currently Amended) A light emitting device comprising:

a light emitting emitting chip; and

a phosphor through which a first light emitting from the light emitting chip passes,

wherein the phosphor comprises a silicate phosphor exciting a second light having a first

centered emission peak using the first light and a sulfide phosphor exciting a third light having a

second centered emission peak using the first light, and

wherein the silicate phosphor has a chemical formula of $Sr_{3-x}SiO_5$: $Eu^{2+}_{x}(0 < x \le 1)$, and

wherein the sulfide phosphor has a chemical formula of $Sr_{1-x}Ga_2S_4$: $Eu^{2+}_{x}(0.001 \le x \le 1)$.

2. (Original) The light emitting device according to claim 1, wherein the first centered

emission peak is in a range of 550 - 600 nm.

3. (Original) The light emitting device according to claim 1, wherein the second centered

emission peak is in a range of 500 - 550 nm.

4-5. (Cancelled)

6. (Original) The light emitting device according to claim 1, wherein the silicate

phosphor and the sulfide phosphor exist at a ratio of 1:1 to 1:9.

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7. (Original) The light emitting device according to claim 1, wherein the phosphor has a particle size of $d_{90} \le 20 \ \mu m$, $5 \le d_{50} \le 10 \ \mu m$.

- 8. (Original) The light emitting device according to claim 1, wherein the light emitting chip emits blue light.
- 9. (Original) The light emitting device according to claim 1, wherein the phosphor is molded in a periphery of the light emitting chip or on the light emitting chip.
- 10. (Original) The light emitting device according to claim 1, wherein the phosphor is manufactured by mixing the phosphor with a light transmitting resin.
- 11. (Original) The light emitting device according to claim 10, wherein the resin is an epoxy resin or a silicon resin.
- 12. (Original) The light emitting device according to claim 1, wherein the silicate phosphor is a yellow series and the sulfide phosphor is a green series.
 - 13. (Original) A phosphor of a light emitting device, comprising:
- a silicate phosphor excited by a light generated by a light emitting chip and having a chemical formula of $Sr_{3-x}SiO_5$: $Eu^{2+}_{x}(0 < x \le 1)$; and

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a sulfide phosphor excited by the light generated by the light emitting chip and having a

chemical formula of $Sr_{1-x}Ga_2S_4$: $Eu^{2+}_{x}(0.001 \le x \le 1)$.

14. (Currently Amended) A-ligth light emitting device comprising:

a substrate;

a light emitting chip emitting a light;

a connection part for electrically connecting the substrate with the light emitting chip;

a phosphor encapsulating the light emitting chip and through which the light passes;

a silicate phosphor contained in the phosphor and having a chemical formula of Sr₃.

 $_{x}SiO_{5}:Eu^{2+}_{x}$ (0 < x \le 1); and

a sulfide phosphor contained in the phosphor and having a chemical formula of Sr₁.

 $_{x}Ga_{2}S_{4}$: $Eu_{x}^{2+}(0.001 \le x \le 1)$.

15. (Original) The light emitting device according to claim 14, wherein when the light

emitting device is a top view type, the silicate phosphor and the sulfide phosphor exist at a ratio

of 1:2 to 1:3.

16. (Original) The light emitting device according to claim 14, wherein when the light

emitting device is a side view type, the silicate phosphor and the sulfide phosphor exist at a ratio

of 1:3 to 1:4.

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- 17. (Currently Amended) A-light light emitting device comprising:
- a leadframe;
- a light emitting chip emitting a light;
- a connection part for electrically connecting the leadframe with the light emitting chip;
- a phosphor encapsulating and molding the light emitting chip and through which the

light passes;

a silicate phosphor contained in the phosphor and having a chemical formula of Sr₃.

$$_{x}SiO_{5}:Eu_{x}^{2+}(0 < x \le 1);$$
 and

a sulfide phosphor contained in the phosphor and having a chemical formula of Sr₁.

$$_{x}Ga_{2}S_{4}:Eu^{2+}_{x}(0.001 \le x \le 1).$$

18-21. (Cancelled)